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## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





# LED Display Product Data Sheet LTC-2621JD

Spec No.: DS30-2000-424

Effective Date: 01/06/2001

Revision: -

**LITE-ON DCC**

**RELEASE**

BNS-OD-FC001/A4

**FEATURES**

- \* 0.28 inch (7 mm) DIGIT HEIGHT.
- \* CONTINUOUS UNIFORM SEGMENTS.
- \* LOW POWER REQUIREMENT.
- \* EXCELLENT CHARACTERS APPEARANCE.
- \* HIGH BRIGHTNESS & HIGH CONTRAST.
- \* WIDE VIEWING ANGLE.
- \* SOLID STATE RELIABILITY.
- \* CATEGORIZED FOR LUMINOUS INTENSITY.

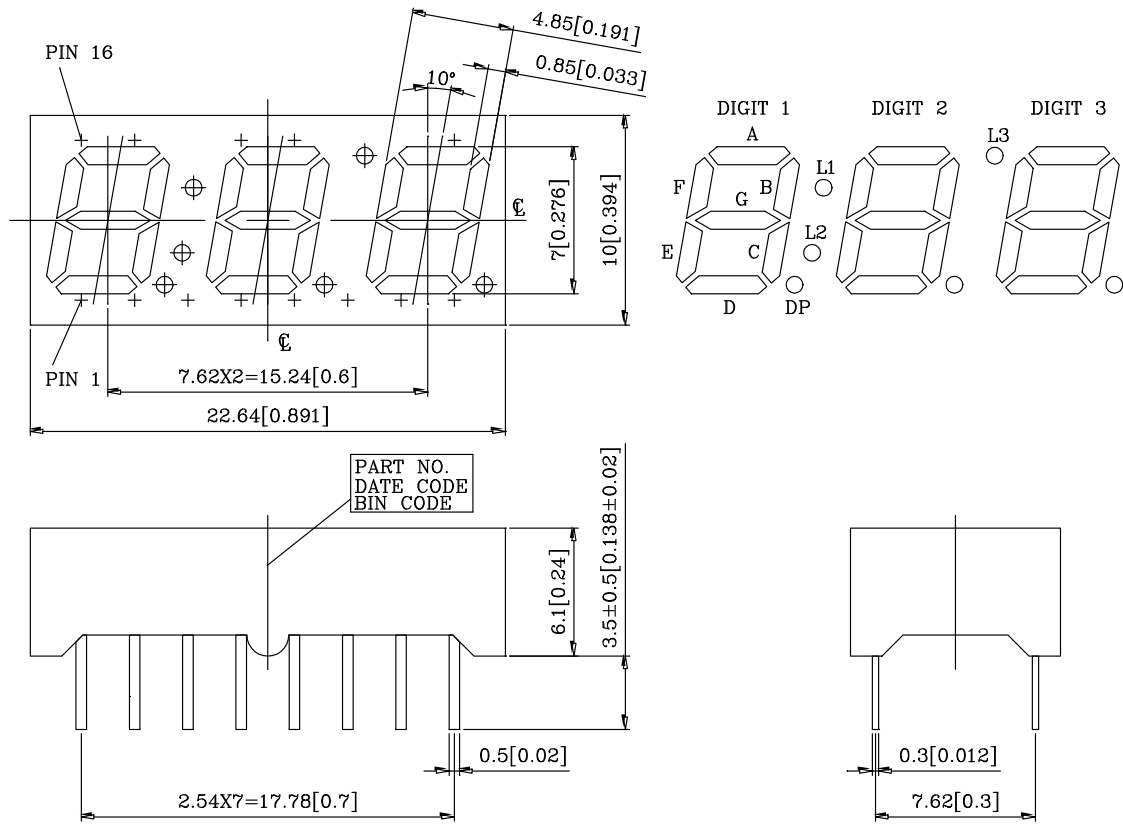
**DESCRIPTION**

The LTC-2621JD is a 0.28 inch (7 mm) height triple digit display. The device utilizes AlInGaP high efficiency Red LED chips, which are made from AlInGaP on a non-transparent GaAs substrate, and have gray face and white segment color.

**DEVICE**

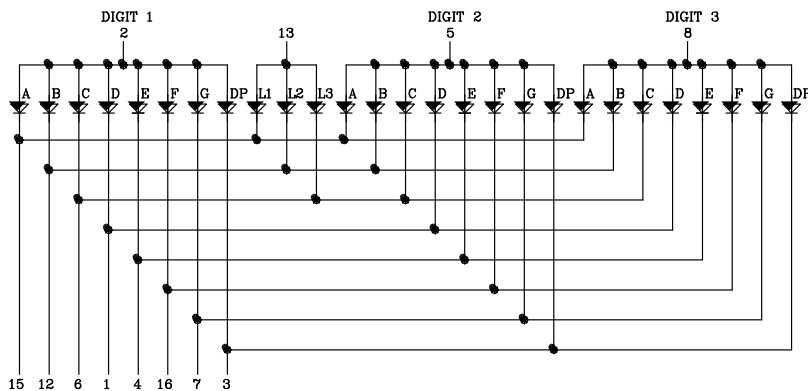
<b>PART NO.</b>	<b>DESCRIPTION</b>
AlInGaP Hi-Eff RED	Multiplex Common Anode Rt.Hand Decimal
LTC-2621JD	

## PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerance is ± 0.25 mm (0.01") unless otherwise noted.

## INTERNAL CIRCUIT DIAGRAM



**PIN CONNECTION**

<b>No.</b>	<b>CONNECTION</b>
1	CATHODE D
2	COMMON ANODE (DIGIT 1)
3	CATHODE D.P.
4	CATHODE E
5	COMMON ANODE (DIGIT 2)
6	CATHODE C , L3
7	CATHODE G
8	COMMON ANODE (DIGIT 3)
9	NO CONNECTION
10	NO PIN
11	NO PIN
12	CATHODE B , L2
13	COMMON ANODE L1 , L2 , L3
14	NO PIN
15	CATHODE A , L1
16	CATHODE F

**ABSOLUTE MAXIMUM RATING AT Ta=25°C**

PARAMETER	MAXIMUM RATING	UNIT
Power Dissipation Per Segment	70	mW
Peak Forward Current Per Segment ( 1/10 Duty Cycle, 0.1ms Pulse Width )	90	mA
Continuous Forward Current Per Segment Derating Linear From 25°C Per Segment	25 0.33	mA mA/°C
Reverse Voltage Per Segment	5	V
Operating Temperature Range	-35°C to +85°C	
Storage Temperature Range	-35°C to +85°C	
Solder Temperature: max 260°C for max 3sec at 1.6mm[1/16inch] below seating plane.		

**ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta=25°C**

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I <sub>v</sub>	200	600		μcd	I <sub>F</sub> =1mA
Peak Emission Wavelength	λ <sub>p</sub>		656		nm	I <sub>F</sub> =20mA
Spectral Line Half-Width	Δλ		22		nm	I <sub>F</sub> =20mA
Dominant Wavelength	λ <sub>d</sub>		640		nm	I <sub>F</sub> =20mA
Forward Voltage Per Segment	V <sub>F</sub>		2.1	2.6	V	I <sub>F</sub> =20mA
Reverse Current Per Segment	I <sub>R</sub>			100	μA	V <sub>R</sub> =5V
Luminous Intensity Matching Ratio	I <sub>v</sub> -m			2:1		I <sub>F</sub> =1mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

## TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

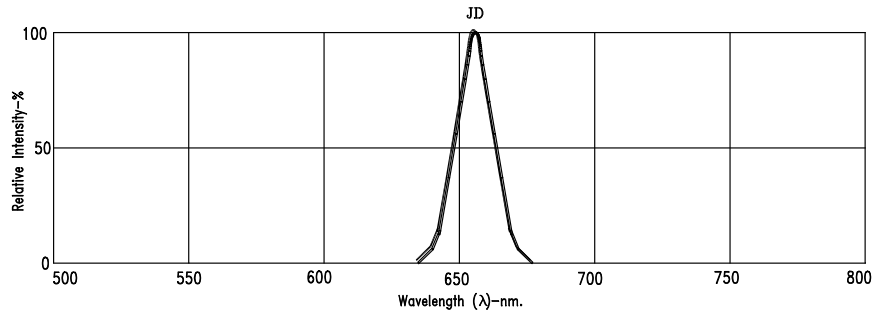


Fig1. RELATIVE INTENSITY VS. WAVELENGTH

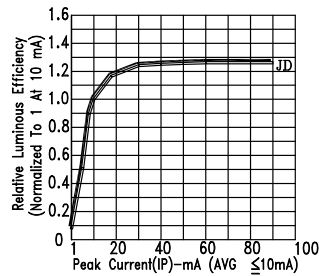


Fig2. RELATIVE LUMINOUS EFFICIENCY (LUMINOUS INTENSITY PER UNIT CURRENT) VS. PEAK CURRENT

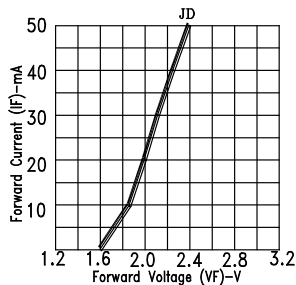


Fig3. FORWARD CURRENT VS. FORWARD VOLTAGE

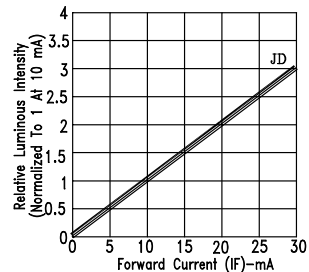


Fig4. RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

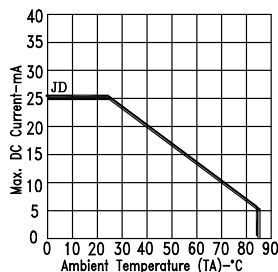


Fig5. MAX. ALLOWABLE DC CURRENT VS. AMBIENT TEMPERATURE.

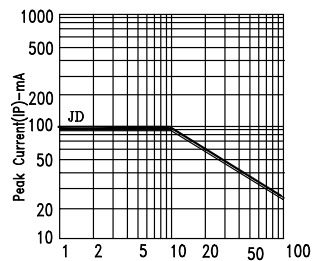


Fig6. MAX. PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE 1KHz)

NOTE : JD=AlInGaP HL-EFF. RED